

# **AXIAL LEADED SILICON RECTIFIER DIODES**

VOLTAGE RANGE: 1250V CURRENT: 1.0 A

#### **Features**

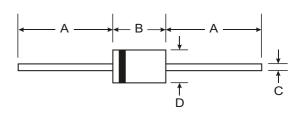
- Molded case feature for auto insertion
- High current capability
- Low leakage current
- High surge capability
- High temperature soldering guaranteed:
   250 °C/10sec/0.375" (9.5mm) lead length at 5 lbs
- tension

### **Mechanical Data**

- Case:JEDEC DO -41,molded plastic
- Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- Polarity: Color band denotes cathode
- Weight: 0.012ounces, 0.34 grams
- Mounting position: Any







DO-41			
Dim	Min	Max	
Α	25.40	_	
В	4.06	5.21	
С	0.71	0.864	
D	2.00	2.72	
All Dimensions in mm			

# Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BY127M	Unit	
Maximum recurrent peak reverse voltage	$V_{RRM}$	1250	V	
Maximum RMS voltage	V <sub>RMS</sub>	875	V	
Maximum DC blocking voltage	V <sub>DC</sub>	1250	V	
Maximum average forw ard rectified current 9.5mm lead length, @T <sub>A</sub> =75°C	I <sub>F(AV)</sub>	1.0	А	
Peak forward surge current  8.3ms single half-sine-wave superimposed on rated load @T <sub>J</sub> =125°C	I <sub>FSM</sub>	30.0	А	
Maximum instantaneous forw ard voltage  @ 1.0 A	V <sub>F</sub>	1.1	V	
Maximum reverse current @T <sub>A</sub> =25°C		5.0	Λ	
at rated DC blocking voltage @T <sub>A</sub> =100°C	I <sub>R</sub>	50.0	μΑ	
Typical junction capacitance (Note1)	С	10	pF	
Typical thermal resistance (Note2)	$R_{\theta JA}$	50	°C/W	
Operating junction temperature range	T <sub>J</sub>	- 55 + 150	$^{\circ}\mathbb{C}$	
Storage temperature range	T <sub>STG</sub>	- 55 + 150	$^{\circ}\mathbb{C}$	

NOTE: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

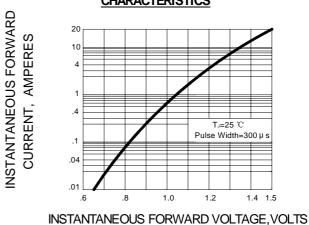
<sup>2.</sup> Thermal resistance from junction to ambient at 0.375"(9.5mm) lead length, P.C.board mounted



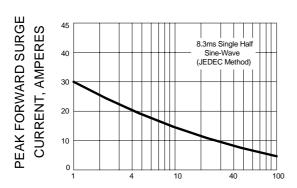
#### FIG.1 - TYPICAL FORWARD CURRENT DERATING CURVE

## 1.0 AVERAGE FORWARD CURRENT 0.8 **AMPERES** 0.6 0.4 Single Phase Half Wave 60Hz Resistive or Inductive Load 0.2 0 150 75 AMBIENT TEMPERATURE, ℃

### FIG.2 - TYPICAL INSTANTANEOUS FORWARD **CHARACTERISTICS**



# FIG.3 – MAXIMUM NON-REPETITIVE FORWARD



# **SURGE CURRENT**

CURRENT, MICRO AMPERES INSTANTANEOUS REVERSE .04

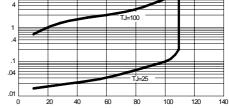


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

NUMBER OF CYCLES AT 60Hz

PERCENT OF RATED PEAK REVERSE VOLTAGE, %

#### FIG.5 - TYPICAL JUNCTION CAPACITANCE

